
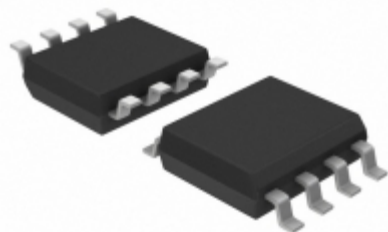


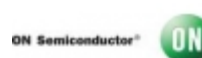

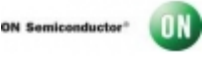
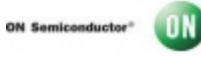


	<h2>NTMD6N03R2G</h2>
	<p>Hersteller-Teilenummer: NTMD6N03R2G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET 2N-CH 30V 6A 8SOIC</p> <p>Datenblätter:  NTMD6N03R2G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 50904 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMD6N03R2G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2N-CH 30V 6A 8SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	50904 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.29W
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOIC
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A
Rds On (Max) @ Id, Vgs	32 mOhm @ 6A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	950pF @ 24V
Verpackung	Tape & Reel (TR)



















































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Sie können auch interessiert sein:

 <p>NTMD6N02R2 AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 20V 3.92A 8SO</p>	 <p>NTMD6N02R2G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 20V 3.92A 8SO</p>	 <p>NTMD6P02 AMI Semiconductor / ON Semiconductor NTMD6P02 ON</p>	 <p>NTMD6N03R2 AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 6A 8SOIC</p>
 <p>NTMD6N03 AMI Semiconductor / ON Semiconductor NTMD6N03 ON</p>	 <p>NTMD6N04 AMI Semiconductor / ON Semiconductor NTMD6N04 ON</p>	 <p>NTMD6N04R2G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 40V 4.6A 8SOIC</p>	 <p>NTMD6N03DR2G ON NTMD6N03DR2G ON</p>

heiße Teile

Mehr

 NTMD3903R2G	 NTMD3N08LR2G	 NTMD3P03	 NTMD3P03R2	 NTMD3P03R2G
 NTMD4102PR2G	 NTMD4184PF	 NTMD4184PFR2G	 NTMD4820N	 NTMD4820NR2G
 NTMD4840N	 NTMD4840NR2G	 NTMD4884NFR2G	 NTMD4N03	 NTMD4N03R2G
 NTMD5836NL	 NTMD5836NLR2G	 NTMD5838NL	 NTMD5838NLR2G	 NTMD6N02
 NTMD6N02DR2G	 NTMD6N02R2G	 NTMD6N03	 NTMD6N03DR2G	 NTMD6N03R2
 NTMD6N04	 NTMD6N04R2G	 NTMD6P02	 NTMD6P02R2	 NTMD6P02R2G
 NTMD6P02R2G.	 NTMD6P02R2SG	 NTMFD4901NF1G	 NTMFD4901NFT1G	 NTMFD4902NF1G
 NTMFD4902NFT1G	 NTMFD4C85NT1G	 NTMFD4C85NTG	 NTMFD4H089NFT1G	 NTMFS4108NT1G
 NTMFS4108NT3G	 NTMFS4119NT3G	 NTMFS4120NT1G	 NTMFS4121NT1G	 NTMFS4701NT1G
 NTMFS4707NT1G	 NTMFS4708NT1G	 NTMFS4709NT1G	 NTMFS4709NT3G	 NTMFS4744NT1G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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